



Associate Degree Program

Specialization	Common
Course Number	020400111
Course Title	Electronic Circuits and Devices
Credit Hours	3
Theoretical Hours	3
Practical Hours	0



جامعة الراهاء التطريهية

وصف المادة الدراسية:

This course covers the basic subjects in electronics and you will study: Semiconductor theory , the diode , special purpose diodes , diode applications , bipolar junction transistor (BJT) , field effect transistor (FET) , operational amplifiers, thyristor and other devices.

أهداف المادة الدراسية:

Upon the completion of the course, the student will be able to:

- 1. Explain the basic structure of atoms.
- 2. Define and discuss semiconductors, conductors, insulators.
- 3. Identify the bias and applications of diode, zener ,varactor, and other special diodes.
- 4. Study of BJT & FET ,oscillators ,operational amplifiers, thyristors and other devices



جامعة البلقاء التطبيقية

الوصف العام:

رقم الوحدة	اسم الوحدة	محتويات الوحدة	الزمن الزمن
1.	Introduction to Semiconductors	 Atomic structure Semiconductors Conductors Insulators Covalent bonds Conduction in semiconductors Intrinsic and extrinsic semiconductors N-type and p- type semiconductors 	1 week
2.	The Diode	 P-N junction Biasing the diode Voltage – current characteristic of diode DC load line Operating point DC and AC resistance Comparison between silicon and germanium diodes Data sheet of diode 	2 weeks
3.	Special – Purpose Diode	 Zener diode (symbol, structure, principle of operation Zener diode applications (regular and limiter) Varactor diode. Light- emitting diode (LED), photodiode 	1 weeks
4.	Applications of The Diode	 Half – wave and full – wave rectifiers Filters and regulators in power supply circuits. 	2 weeks
5.	Bipolar Junction Transistor (BJT)	 Introduction Structure and principle of operation Characteristics and parameters. Regions of operation 	2 weeks



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6.	Field – Effect Transistor(FET)	 The DC operation point)load line) BJT as an amplifier and as switch Voltage divider bias and other bias methods Basic circuits connection (C.E, C.C, C.B) amplifier Data sheet of a BJT Introduction. Structure and principle of operation of junction field effect transistor (JFET). JFET characteristics, Parameters and biasing. Structure and principle of operation of metal oxide semiconductor field effect transistor (MOSFET). Enhancement and depletion types. MOSFET characteristics, Parameters and biasing. FET amplification, connections modes (C.S, C.D, C.G,) amplifiers, data sheet of a JFET and a MOSFET. 	2 week
7.	Oscillators	 Introduction Negative and positive feedback, (basic circuit, principle of operation, oscillation frequency calculation for the following oscillators. Phase – shift oscillator Colpitts and Hartley oscillators 	1 week
8.	Operational Amplifiers	 Colpits and Hartley oscillators Symbol, terminals and basic opamp representations (idea and practical) 	2 week



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9.	Thyristor and Other Devices	 Structure ,principle of operation Characteristics curves and applications of the following devices: (Four – layer device, SCR (Silicon – controlled rectifier), siac, triac, Uninjunction transistor (UJT), and phototransistor 	2 week
10.	Introduction to Electronic Measurements	 Applications of oscilloscope in electronic measurements 	1 week

Lectures

الكتب و المراجع:

- 1. Thomas L. Floyd, electrical devices, prentice hall international, 6th edition, 2002.
- 2. Basic operational Amplifiers and Linear Integrated Circuits , David Buchla ,Prentice Hall , 1999.
- 3. Electronics fundamental and Experiments, Cynthia B. Leshin, David Buchla, Tjomas L. Floyd, prentice hall international ,1999.



Associate Degree Program

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Electronic Circuits and Devices Lab.		
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جامعة البلهاء التطبيهية

وصف المادة الدراسية:

❖ Lab in support of the basic electronics course, experiments in basic electronics have to cover all electronics devices (diode, zener diode, diode applications, BJT,op − amp ,oscillators ,SCR).

أهداف المادة الدر اسبة:

Upon the completion of the course, the student will be able to:

- 1. Become familiar with electronics devices and using data sheet.
- 2. Demonstrate how to test electronic devices by using AVO meter or through DC measurements.
- 3. Construct electronic circuit.
- 4. Investigate characteristics curves.
- 5. Calculate the value the values of currents and voltage and compare them with measured values



جامعة البلغاء التطبيقية

الوصف العام:

			وعنت المام.
رقم الوحدة	اسم الوحدة	محتويات الوحدة	الزمن
1.	The diode	 Forward and reverse biasing. 	2 weeks
		 Characteristic curve. 	
		Data sheet.	
2.	The zener Diode.	 Breakdown voltage. 	2 weeks
		Regulation.	
		 Characteristic curve. 	
		Data sheet	
3.	Rectification Circuits with	 Half- wave and full- wave. 	1 week
	Filter and Regulator	Ripple factor.	
		 Line and load regulation 	
4.	A BJT testing by using AVO		1 week
	meter, and how to determine		
	the specifications of transistor		
	through data sheets		
5.	A BJT with Voltage – Divider		1 week
	Bias		
6.	A BJT as a switch		1 week
7.	Common Emitter Amplifier		1 week
	Circuit		
8.	Common collector Amplifier		1 week
	circuit		
9.	Common Base Amplifier		1 week
	Circuits		
10.	Common source Amplifier		1 week
	Circuits		
11.	Operational Amplifier as		1 week
	Inverting and Noninverting		
	Amplifier		
12.	Operational Amplifier as		1 week
	Differentiator and Integrator		
13.	RC phase-shift Oscillator		1 week
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14.	SCR as a switch	1 week

طرق التقييم المستخدمة:

التاريخ	نسبة الامتحان من العلامة الكلية	الامتحانات
	30%	التقارير
	20%	الامتحان المتوسط
	50%	الامتحانات النهائية

الكتب و المراجع:

- 1. Instructional Lab. Sheets
- 2. Thomas L. Floyd "Principles of electric circuits" Electron flow version prentice hall International eighth edition 2006.
- 3. Robert L. Boy listed Introductory circuit analysis prentice hall International 1997.
- 4. Experiments in electronics Fundamentals and electric circuits fundamentals David Buchla -. prentice hall 2000.